



IRF3709PBF Information

Part Number IRF3709PBF

Manufacturer Infineon Technologies

Category Discrete Semiconductor Products

Transistors - FETs, MOSFETs - Single

Description MOSFET N-CH 30V 90A TO-220AB

TO-220-3 **Package**

For the pricing/inventory/lead time, please contact

Website: https://www.heisener.com For Reference Only

E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









IRF3709PBF Specifications

Manufacturer Part Number	IRF3709PBF
Manufacturer	Infineon Technologies
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	TO-220-3
Series	HEXFET?
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	30V
Current - Continuous Drain (Id) @ 25°C	90A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	4.5V, 10V
Vgs(th) (Max) @ Id	3V @ 250μA
Gate Charge (Qg) (Max) @ Vgs	41nC @ 5V
Input Capacitance (Ciss) (Max) @ Vds	2672pF @ 16V
Vgs (Max)	±20V
FET Feature	-
Power Dissipation (Max)	3.1W (Ta), 120W (Tc)
Rds On (Max) @ Id, Vgs	9 mOhm @ 15A, 10V
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Through Hole
Supplier Device Package	TO-220AB
Package / Case	TO-220-3
	Report errors?

IRF3709PBF Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

IRF3709PBF Payment Methods



















IRF3709PBF Shipping Methods













If you have any question about IRF3709PBF, please do not hesitate to contact us!

Website: https://www.heisener.com E-mail: salesdept@heisener.com